

HD74HC280

9-bit Odd/Even Parity Generator/Checker

REJ03D0606–0200 (Previous ADE-205-484) Rev.2.00 Jan 31, 2006

Description

This parity generator/checker features odd/even outputs to facilitate operation of either odd or even parity applications. The word length capability is easily expanded by cascading devices.

Features

- High Speed Operation: t_{pd} (Data to Σ Even or Σ Odd) = 22 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74HC280P	DILP-14 pin	PRDP0014AB-B (DP-14AV)	Ρ	_	
HD74HC280FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)	

Note: Please consult the sales office for the above package availability.

Function Table

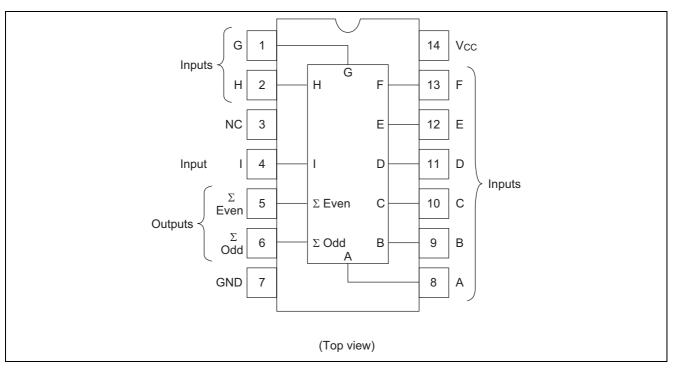
Number of inputs	Outputs					
A through I that are high	ΣEven	ΣOdd				
0, 2, 4, 6, 8	Н	L				
1, 3, 5, 7, 9	L	Н				

H : High level

L : Low level



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
Input / Output voltage	Vin, Vout	–0.5 to V _{CC} +0.5	V
Input / Output diode current	I _{IK} , I _{OK}	±20	mA
Output current	Ι _Ο	±25	mA
V _{CC} , GND current	I _{CC} or I _{GND}	±50	mA
Power dissipation	PT	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions	
Supply voltage	Vcc	2 to 6	V		
Input / Output voltage	Vin, Vout	0 to V _{CC}	V		
Operating temperature	Та	-40 to 85	°C		
Input rise / fall time ^{*1}	tr, tr	0 to 1000	ns	V _{CC} = 2.0 V	
		0 to 500		V _{CC} = 4.5 V	
		0 to 400]	V _{CC} = 6.0 V	

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



ltem	Symbol	V _{cc} (V)	Ta = 25°C		Ta = -40 to+85°C		l Init	Test Conditions	
			Min	Тур	Max	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5			1.5		V	
		4.5	3.15	—		3.15			
		6.0	4.2	_		4.2	_		
	VIL	2.0	_	_	0.5	—	0.5	V	
		4.5	_	_	1.35	—	1.35		
		6.0	_	_	1.8	—	1.8		
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9		V	Vin = V _{IH} or V _{IL} $I_{OH} = -20 \ \mu A$
		4.5	4.4	4.5	_	4.4			
		6.0	5.9	6.0	_	5.9			
		4.5	4.18	_	_	4.13			$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63			I _{OH} = -5.2 mA
	V _{OL}	2.0	_	0.0	0.1	—	0.1	V	$Vin = V_{IH} \text{ or } V_{IL} I_{OL} = 20 \ \mu A$
		4.5	_	0.0	0.1	—	0.1		
		6.0	_	0.0	0.1	—	0.1		
		4.5	_	_	0.26	—	0.33		$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	—	0.33		I _{OL} = 5.2 mA
Input current	lin	6.0	_	_	±0.1	—	±1.0	μΑ	Vin = V _{CC} or GND
Quiescent supply	I _{CC}	6.0		_	4.0	_	40	μΑ	Vin = V_{CC} or GND, lout = 0 μ A
current									

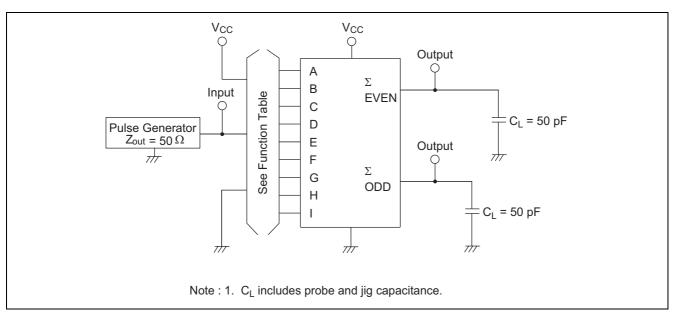
Electrical Characteristics

Switching Characteristics

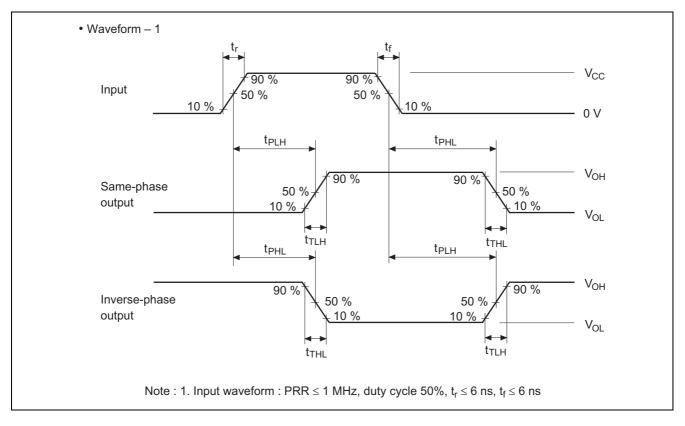
 $(C_L = 50 \text{ pF}, \text{ Input } t_r = t_f = 6 \text{ ns})$

ltem	Symbol	V _{cc} (V)	Ta = 25°C		Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Тур	Max	Min	Max	onn	Test conditions
Propagation delay	t _{PLH}	2.0	l		205	_	255	ns	Data to Σ Even or Σ Odd
time	t _{PHL}	4.5		22	41	_	51		
		6.0	_	_	35	—	43		
Output rise/fall	t _{TLH}	2.0	_	_	75	—	95	ns	
time	t _{THL}	4.5	_	5	15	—	19		
		6.0	_	_	13	_	16		
Input capacitance	Cin			5	10	—	10	pF	

Test Circuit

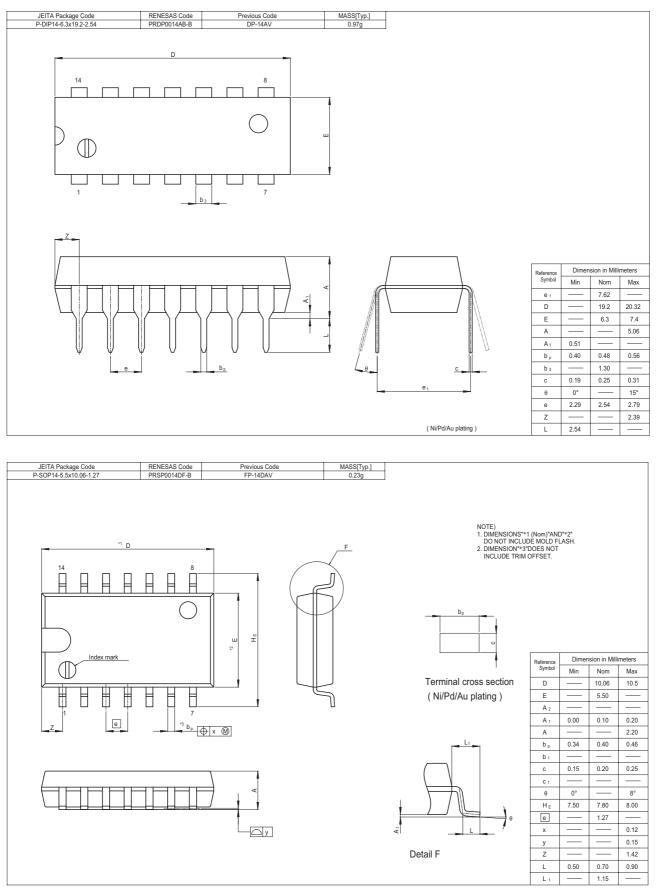


Waveforms





Package Dimensions





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